



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary (Typ. @ V_{GS} = -4.5V, T_A = +25°C)

| BV _{DSS} | R _{DS(ON)} | Qg | Q_{gd} | ID |
|-------------------|---------------------|-------|----------|-------|
| -12V | 0.065Ω | 2.5nC | 0.6nC | -3.3A |

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management
- Load Switch
- Battery Protection



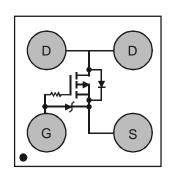
Features

- LD-MOS Technology with the Lowest Figure of Merit: $R_{DS(ON)} = 0.065\Omega \text{ to Minimize On-State Losses} \\ Q_g = 2.5nC \text{ for Ultra-Fast Switching}$
- V_{gs(TH)} = -0.5V Typ. for a Low Turn-On Potential
- CSP with Footprint 1.0mm x 1.0mm
- Height = 0.62mm for Low Profile
- ESD = 3kV HBM Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: U-WLB1010-4
- Terminal Connections: See Diagram Below
- Weight: 0.0018 grams (Approximate)

U-WLB1010-4



Top View Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|-------------|-------------------|
| DMP1081UCB4-7 | U-WLB1010-4 | 3,000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

U-WLB1010-4



7A = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

| Year | 201 | 6 | 2017 | | 2018 | 20 |)19 | 2020 | | 2021 | 7 | 2022 |
|-------|-----|-----|------|-----|------|-----|-----|------|-----|------|-----|------|
| Code | D | | Е | | F | (| G | Н | | ! | | J |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | J |



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|------------------|--|-----------------|--------------|---|
| Drain-Source Voltage | V _{DSS} | -12 | V | | |
| Gate-Source Voltage | | | V_{GSS} | -6 | V |
| Continuous Drain Current (Note 5) V _{GS} = -4.5V | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | -3.3 -2.7 | А |
| Continuous Drain Current (Note 5) V _{GS} = -2.5V | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | -3.0 -2.4 | А |
| Pulsed Drain Current (Note 6) | | | I _{DM} | 20 | Α |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 7) | P _D | 0.82 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 7) | $R_{\theta JA}$ | 150 | °C/W |
| Thermal Resistance, Junction to Case @T _C = +25°C (Note 7) | R ₀ JC | 42.66 | °C/W |
| Power Dissipation (Note 5) | P _D | 1.59 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5) | $R_{\theta JA}$ | 80.29 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

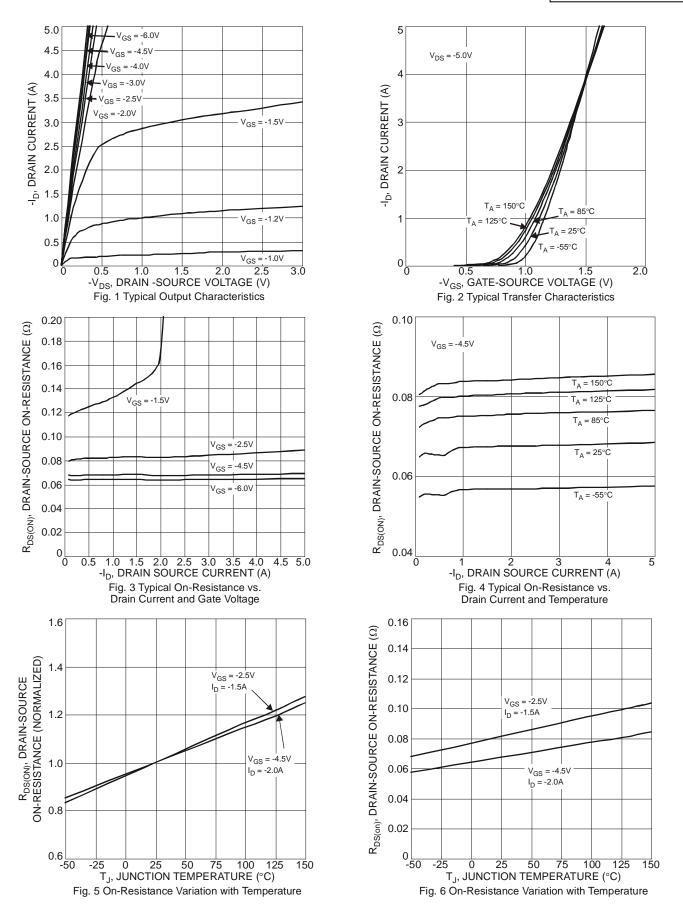
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-------|-------|-------|------|--|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -12 | - | - | V | $V_{GS} = 0V, I_D = -250\mu A$ | |
| Gate-Source Breakdown Voltage | BV _{GSS} | -6.0 | - | - | V | $V_{DS} = 0V, I_{G} = -250\mu A$ | |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | - | - | -1 | μΑ | $V_{DS} = -9.6V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | - | - | -100 | nA | $V_{GS} = -6V$, $V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.35 | -0.5 | -0.65 | V | $V_{DS} = V_{GS}$, $I_D = -250\mu A$ | |
| | | - | 0.065 | 0.08 | | $V_{GS} = -4.5V, I_D = -500mA$ | |
| Static Drain-Source On-Resistance | B-s/s/ | - | 0.077 | 0.1 | Ω | $V_{GS} = -2.5V$, $I_D = -500$ mA | |
| Static Diani-Source On-Nesistance | R _{DS(ON)} | - | 0.108 | 0.13 | 22 | $V_{GS} = -1.5V, I_D = -500mA$ | |
| | | - | 0.4 | 10 | | $V_{GS} = -0.9V, I_D = -100mA$ | |
| Forward Transfer Admittance | Y _{fs} | - | 4 | - | S | $V_{DS} = -6V, I_{D} = -500mA$ | |
| Diode Forward Voltage | V_{SD} | - | -0.6 | -1.0 | V | $V_{GS} = 0V, I_{S} = -500mA$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | |
| Input Capacitance | C _{iss} | - | 213 | 350 | | \\ G\\ \\ G\\ | |
| Output Capacitance | Coss | - | 119 | 250 | pF | $V_{DS} = -6V, V_{GS} = 0V,$ f = 1.0MHz | |
| Reverse Transfer Capacitance | Crss | - | 54.4 | 90 | | 1 = 1.01/11/12 | |
| Total Gate Charge | Q_g | - | 2.5 | 5 | | | |
| Gate-Source Charge | Qgs | 1 | 0.3 | 1 | nC | $V_{GS} = -4.5V, V_{DS} = -6V,$ | |
| Gate-Drain Charge | Q_{gd} | | 0.6 | - | 110 | $I_D = -500 \text{mA}$ | |
| Gate Charge at V _{TH} | $Q_{g(TH)}$ | 1 | 0.15 | 1 | | | |
| Turn-On Delay Time | t _{D(ON)} | - | 16.7 | - | | | |
| Turn-On Rise Time | t _R | - | 20.6 | - | ns | $V_{DS} = -6V, V_{GS} = -2.5V,$ | |
| Turn-Off Delay Time | t _{D(OFF)} | - | 38.4 | - | ns | $R_G = 20\Omega$, $I_D = -500 \text{mA}$ | |
| Turn-Off Fall Time | t _F | - | 28.4 | - | | | |
| Reverse Recovery Charge | Q_{RR} | - | 2.0 | - | nC | $V_{DD} = -4.0V$, $I_F = -0.5A$, | |
| Reverse Recovery Time | t _{RR} | - | 9.5 | - | ns | di/dt =100A/µs | |

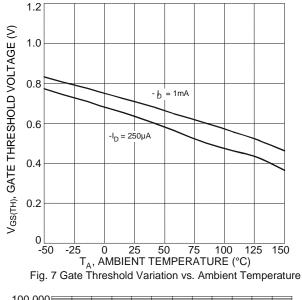
Notes:

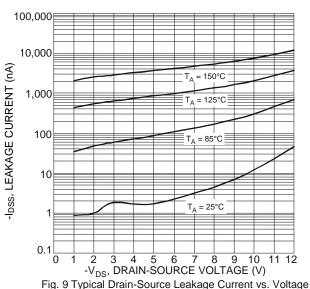
- Device mounted on FR-4 material with 1inch² (6.45cm²), 2oz. (0.071mm thick) Cu.
 Repetitive rating, pulse width limited by junction temperature.
 Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.

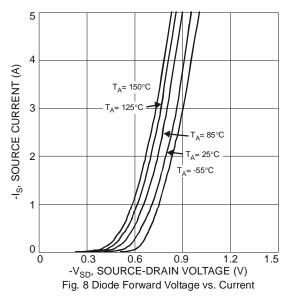


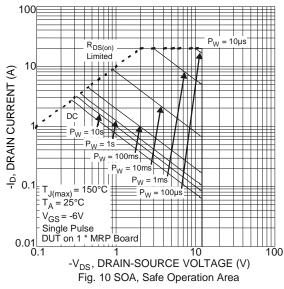


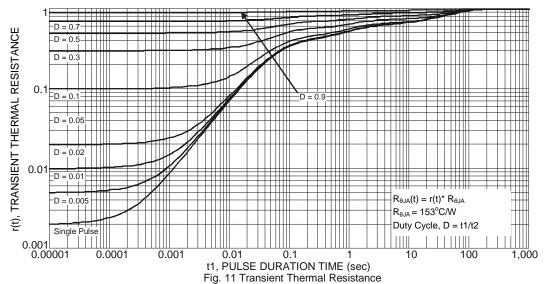










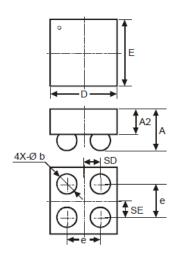




Package Outline Dimension

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1010-4

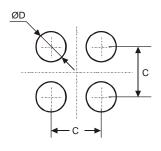


| U-WLB1010-4 | | | | | | |
|----------------------|------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| D | 0.95 | 1.05 | 1.00 | | | |
| Ε | 0.95 | 1.05 | 1.00 | | | |
| Α | - | 0.62 | _ | | | |
| A2 | _ | _ | 0.38 | | | |
| b | 0.25 | 0.35 | 0.30 | | | |
| е | - | - | 0.50 | | | |
| SD | _ | _ | 0.25 | | | |
| SE | _ | _ | 0.25 | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1010-4



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 0.50 |
| D | 0.25 |



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